Correction to: Separation and enrichment mechanism of C54–TiSi₂ from hypoeutectic Ti–65 wt.% Si alloy during directional solidification via alternating electromagnetic fields

Kui-song Zhu^{1,2,3} · Jing-fei Hu¹ · Wen-hui Ma^{1,3} · Kui-xian Wei¹ · Yong-nian Dai^{1,3}

Published online: 23 March 2020
© China Iron and Steel Research Institute Group 2020

Correction to: J. Iron Steel Res. Int.
<https://doi.org/10.1007/s42243-020-00365-5>

The original version of this article unfortunately contained a mistake. Figure 7 was incorrect. The corrected figure is given below.

The original article can be found online at <https://doi.org/10.1007/s42243-020-00365-5>.

✉ Wen-hui Ma
mwhsilicon@126.com

✉ Kui-xian Wei
kxwei2008@hotmail.com

¹ The National Engineering Laboratory for Vacuum Metallurgy, State Key Laboratory of Complex Nonferrous Metal Resources Clean Utilization, Kunming University of Science and Technology, Kunming 650093, Yunnan, China

² College of Vanadium and Titanium, Panzhihua University, Panzhihua 617000, Sichuan, China

³ Key Laboratory for Nonferrous Vacuum Metallurgy of Yunnan Province, Engineering Research Center for Silicon Metallurgy and Silicon Materials of Yunnan Provincial Universities, Kunming University of Science and Technology, Kunming 650093, Yunnan, China